

AOZ6233 0.35Ω Low-Voltage Dual-SPDT Analog Switch

General Description

The AOZ6233 is a 0.35 Ω low-voltage Dual Single Pole Double Throw (SPDT) analog switch. The AOZ6233 operates from a single 1.65V to 3.6V supply. It features an ultra-low On Resistance of 0.35 Ω at a +2.7V supply and 25°C. The AOZ6233 is designed for break-beforemake operation.

Features

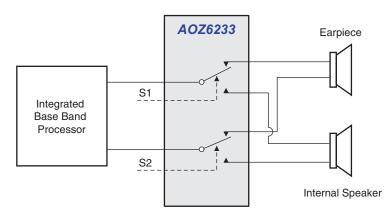
- Typical 0.35 Ω On Resistance (R_{ON}) for +2.7V supply
- 0.15Ω maximum R_{ON} flatness for +2.7V supply
- 1.6mm x 2.1mm QFN package
- Broad V_{CC} operating range
- Low THD (0.02% typical for 32Ω load)
- High current handling capability (350mA continuous current under 3.3V supply)

Applications

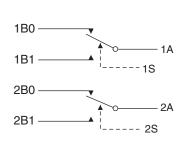
- Cell phone
- PDA
- Portable media player



Typical Application



Pin Configuration





Ordering Information

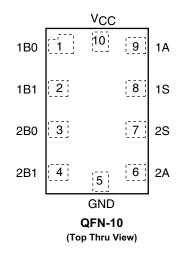
Part Number	Ambient Temperature Range	Package	Environmental
AOZ6233QI	-40°C to +85°C	QFN-10	RoHS Compliant
			Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration



Pin Description

Pin Name	Function
1A, 2A, 1B0, 1B1, 2B0, 2B1	Data Ports
1S, 2S	Control Input

Truth Table

Logic Input	Function
0	B0 Connected to A
1	B1 Connected to A

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +5.5V
V _S	Switch Voltage ⁽¹⁾	-0.5 to V _{CC} + 0.5V
V _{IN}	Input Voltage ⁽¹⁾	-0.5 to V _{CC}
Ι _{ΙΚ}	Minimum Input Diode Current ⁽²⁾	-50mA
I _{SW}	Switch Current	350mA
I _{SWPEAK}	Peak Switch Current (Pulsed at 1ms duration, <10% Duty Cycle)	500mA
T _{STG}	Storage Temperature Range	-65°C to +150°C
Т _Ј	Maximum Junction Temperature	+150°C
ΤL	Lead Temperature (Soldering, 10 seconds)	+260°C
ESD	Human Body Model	8000V
	Charged Device Model	1000V

Recommend Operating Ratings

The device is not guaranteed to operate beyond the Maximum Operating Ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	1.65V to +3.6V
V _{IN}	Control Input Voltage ⁽³⁾	0V to V _{CC}
V _{SW}	Switch Input Voltage	0V to V _{CC}
T _A	Operating Temperature	-40°C to +85°C

Notes:

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

2. Negative current should not exceed minimum negative value.

3. Unused inputs must be held HIGH or LOW. They may not float.



DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
V _{IH}	Input Voltage HIGH		2.7 to 3.6	2.0			V
			2.3 to 2.7	1.7			
			1.65 to 1.95	$0.65 \times V_{CC}$			
V _{IL}	Input Voltage LOW		2.7 to 3.6			0.8	V
			2.3 to 2.7			0.7	
			1.65 to 1.95			$0.35 \mathrm{xV_{CC}}$	
I _{IN}	Control Input Leakage	$V_{IN} = 0V$ to V_{CC}	1.65 to 3.6	-0.5		0.5	μA
I _{NO(OFF)} , I _{NC(OFF)}	Off-Leakage Current of Port nB_0 and nB_1	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
I _{A(ON)}	On Leakage Current of Port 1A and 2A	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
R _{ON}	Switch On Resistance ⁽⁴⁾ See Figure 1	I _{OUT} = 100mA, nB0 or nB ₁ = 0V, 0.7V, 2.0V, 2.7V	2.7		0.35	0.60	Ω
		I _{OUT} = 100mA, nB0 or nB1 = 0V, 0.7V, 1.6V, 2.3V	2.3		0.40	0.70	
		I _{OUT} = 100mA, nB0 or nB1 = 0.8V	1.65		1.0	3.0	
ΔR_{ON}	On Resistance Matching	I _{OUT} = 100mA, nB0 or	2.7		0.040	0.075	Ω
	Between Channels ⁽⁵⁾	nB1 = 0.7V	2.3		0.040	0.080	
			1.65		0.1		
R _{FLAT(ON)}	On Resistance Flatness ⁽⁶⁾	I _{OUT} = 100mA, nB0 or	2.7			0.15	Ω
		$nB1 = 0V$ to V_{CC}	2.3			0.3	1
			1.65		1.6		1
I _{CC}	Quiescent Supply Current	$V_{IN} = 0V \text{ or } V_{CC}, I_{OUT} = 0A$	3.6	-500		500	nA
I _{CCT}	Increase in I _{CC} per Input	V _{IN} = 1.8V	3.6		75		μA
		V _{IN} = 2.6V	1		5		1

Notes:

4. On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.

5. $\Delta R_{ON} = R_{ONmax} - R_{ONmin}$ measured at identical V_{CC}, temperature, and voltage.

6. Flatness is defined as the difference between the maximum and minimum value of R_{ON} over the specified range of conditions.



AC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	ol Parameter Condition		V _{CC} (V)	Min.	Тур.	Max.	Units
t _{ON}	Turn-On Time	nB0 or nB1 = 1.5V, $R_L = 50\Omega$,	2.7 to 3.6		40.0	50.0	ns
		C _L = 35pF			50.0	55.0	
			1.65 to 1.95		75.0	90.0	
t _{OFF}	Turn-Off Time	nB0 or nB1 = 1.5V, $R_{L} = 50\Omega$,	2.7 to 3.6		10.0	25.0	ns
		C _L = 35pF	2.3 to 2.7		20.0	25.0	
			1.65 to 1.95		50.0	55.0	
t _{BBM}	Break-Before-Make Time	nB0 or nB1 = 1.5V, $R_{L} = 50\Omega$,	2.7 to 3.6	2.0	17.0		ns
		C _L = 35pF		2.0	15.0		
			1.65 to 1.95	2.0	12.0		
Q	Charge Injection	$\begin{array}{l} C_{L} = 100pF, \ V_{GEN} = 0V, \\ R_{GEN} = 0\Omega \end{array}$	1.65 to 3.6		9.0		рС
OIRR	Off Isolation	$f = 100 \text{kHz}, \text{R}_{\text{L}} = 50\Omega,$ $\text{C}_{\text{L}} = 5 \text{pF} \text{ (Stray)}$	1.65 to 3.6		-95		dB
Xtalk	Crosstalk	$f = 100 \text{kHz}, \text{R}_{\text{L}} = 50\Omega,$ $C_{\text{L}} = 5\text{pF} \text{ (Stray)}$	1.65 to 3.6		-95		dB
BW	-3dB Bandwidth	$R_L = 50\Omega$	1.65 to 3.6		45.0		MHz
THD	Total Harmonic Distortion	$ \begin{array}{l} R_{L} = 32\Omega, \ V_{IN} = 2V_{pk-pk}, \\ f = 20Hz \ to \ 20kHz \end{array} $	2.7 to 3.6		0.024		%
		$\begin{aligned} R_{L} &= 32\Omega, V_{IN} = 1.5V_{pk-pk}, \\ f &= 20Hz \text{ to } 20kHz \end{aligned}$	2.3 to 2.7		0.015		
		$\label{eq:RL} \begin{split} R_{L} &= 32\Omega, \ V_{IN} = 1.2V_{pk-pk}, \\ f &= 20Hz \ to \ 20kHz \end{split}$	1.65 to 1.95		0.35		

Capacitance

Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
C _{IN}	Control Pin Input Capacitance	f = 1MHz	0.0		4		pF
C _{OFF}	B Port Off Capacitance	f = 1MHz	3.3		22		pF
C _{ON}	A Port On Capacitance	f = 1MHz	3.3		140		pF



Typical Performance Characteristics

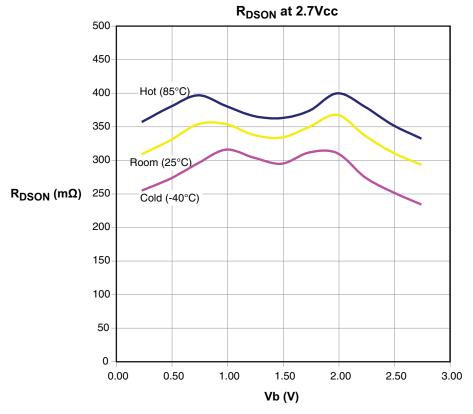
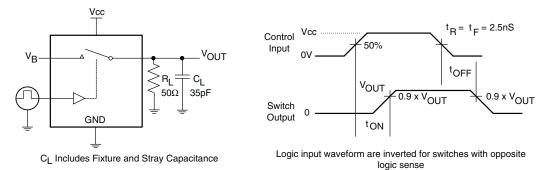
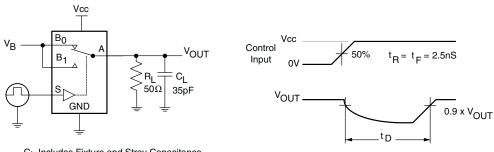


Figure 1. Switch On Resistance

AC Loading and Waveforms







CL Includes Fixture and Stray Capacitance



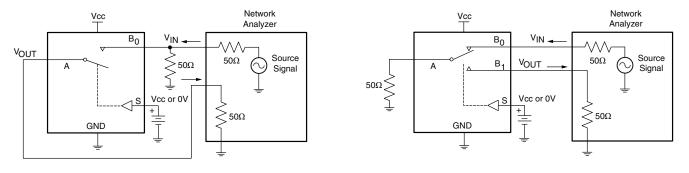
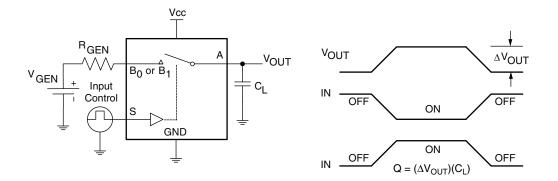


Figure 3. Off Isolation

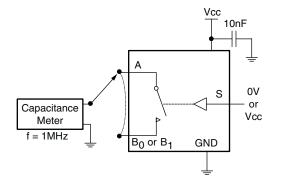




AC Loading and Waveforms (continued)







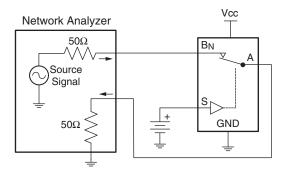


Figure 6. ON/Off Capacitance Measurement

Figure 7. Bandwidth

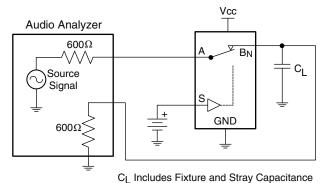
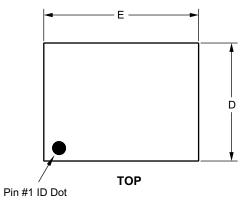
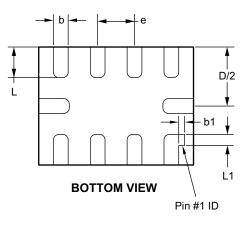
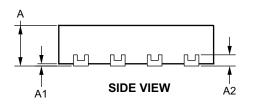


Figure 8. Harmonic Distortion

Package Dimensions, QFN-10



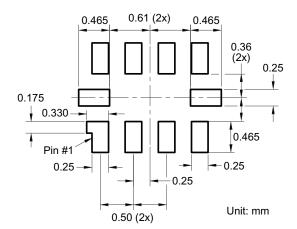




Symbols	Min.	Nom.	Max.			
А	0.50	0.55	0.60			
A1	0.00		0.05			
A2	0.152 REF.					
b	0.15	0.25				
b1	0.08 REF.					
D	1.55	1.65				
E	2.05	2.15				
е	0).50 BSC	;			
L	0.365 0.415 0.465					
L1	0.15 REF.					

Dimensions in inches

Min.	Nom.	Max.								
0.020	0.022	0.024								
0.00	—	0.002								
0.006 REF.										
0.006	0.010									
0.003 REF.										
0.061	0.065									
0.081	0.085									
0	.020 BS	С								
0.014 0.016 0.01										
0.	.006 REI	=.								
	0.020 0.00 0.006 0.061 0.081 0.081 0.014	0.020 0.022 0.00 −− 0.006 REF 0.006 0.008 0.003 REF 0.061 0.063 0.081 0.083 0.081 0.083								

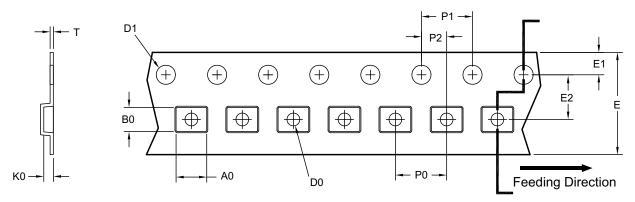


Note:

1. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

Tape and Reel Dimensions, QFN-10

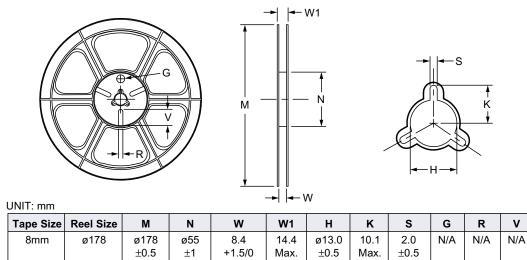
Carrier Tape



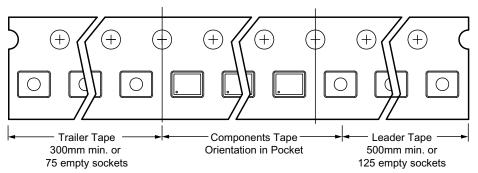
UNIT: mm

Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
QFN 2.1 x 1.6	0.76	1.21	0.53	0.50	1.5	8.00	1.75	3.50	4.00	4.00	2.00	0.254
(8mm)	±0.05	±0.05	±0.05	±0.05	±0.10	+0.30/-0.10	±0.10	±0.05	±0.10	±0.10	±0.05	±0.02

Reel

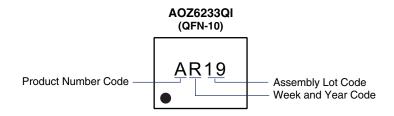


Leader/Trailer and Orientation





Part Marking



This datasheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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